



TECHNICAL DATA DATA SHEET 816, REV. -

HERMETIC POWER MOSFET N-CHANNEL, LOGIC LEVEL

- 60 VOLT, 0.05 OHM, 30A MOSFET
- Fast Switching
- Low R_{DS (on)}
- Logic Level Gate Driver

MAXIMUM RATINGS

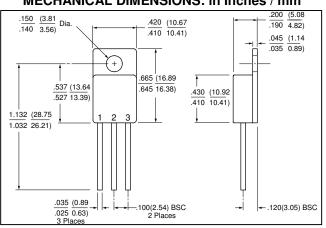
ALL RATINGS ARE AT $T_{A} = 25^{\circ}$ C UNLESS OTHERWISE SPECIFIED.

RATING	SYMBOL	MIN.	TYP.	MAX.	UNITS
GATE TO SOURCE VOLTAGE	V _{GS}	-	-	±20	Volts
CONTINUOUS DRAIN CURRENT $@ T_c = 25^{\circ}C$	I _D	-	-	20*	Amps
PULSED DRAIN CURRENT $@ T_C = 25^{\circ}C$	I _{DM}	-	-	110	Amps(pk)
OPERATING AND STORAGE TEMPERATURE	T _{OP} /T _{STG}	-55	-	+175	°C
TERMAL RESISTANCE JUNCTION TO CASE	$R_{\theta JC}$	-	-	1.32	°C/W
TOTAL DEVICE DISSIPATION @ $T_c = 25^{\circ}C$	P _D	-	-	110	Watts

ELECTRICAL CHARACTERISTICS

		-		
BV _{DSS}	60	-	-	Volts
V _{GS(th)}	1.0	-	2.0	Volts
R _{DS(ON)}	-	-	0.055	Ω
			0.075	
	-	-		
I _{DSS}			25	μA
			250	
I _{GSS}	-	-	±100	nA
Qg	-	-	35	nC
Q _{gs}			7.1	
Q _{gd}			25	
t _{d(ON)}	-	14	-	nsec
t _r				
$t_{d(OFF)}$				
t _f		56		
V _{SD}	-	-	1.6	Volts
t _{rr}	-	120	180	nsec
C _{iss}	-	1600	-	pF
C _{oss}		660		
C _{rss}		170		
	$\begin{array}{c} V_{GS(th)} \\ \hline R_{DS(ON)} \\ \hline I_{DSS} \\ \hline I_{GSS} \\ \hline Q_{gs} \\ Q_{gs} \\ Q_{gd} \\ \hline t_{d(ON)} \\ t_r \\ t_{d(OFF)} \\ t_f \\ \hline V_{SD} \\ \hline t_{rr} \\ \hline C_{iss} \\ C_{oss} \\ \hline \end{array}$	$\begin{array}{c c c c c c c } V_{GS(th)} & 1.0 \\ \hline V_{GS(0N)} & - \\ \hline \\ R_{DS(ON)} & - \\ \hline \\ I_{DSS} & - \\ \hline \\ I_{GSS} & - \\ \hline \\ I_{GSS} & - \\ \hline \\ Q_{gs} & - \\ Q_{gs} & - \\ Q_{gs} & - \\ Q_{gs} & - \\ \hline \\ Q_{gs} & - \\ Q_{gs} & - \\ \hline \\ Q_{gs} & - \\ Q_{gs} & - \\ \hline \\ Q_{gs} & - \\ Q_{gs} & - \\ \hline \\ Q_{gs} & - \\ Q_{gs} & - \\ \hline \\ Q_{gs} & - \\ Q_{gs} & - \\ \hline \\ C_{iss} & - \\ \hline \\ C_{iss} & - \\ \hline \\ C_{iss} & - \\ \hline \end{array}$	$\begin{array}{c c c c c c c c } V_{GS(th)} & 1.0 & - & \\ \hline V_{GS(th)} & 1.0 & - & \\ \hline R_{DS(ON)} & - & - & \\ \hline I_{DSS} & - & - & \\ \hline I_{GSS} & - & - & \\ \hline I_{GSS} & - & - & \\ \hline Q_{gs} & - & - & \\ \hline 170 & - & 14 & \\ \hline 170 & - & 14 & \\ \hline 170 & - & 14 & \\ \hline 170 & - & 120 & \\ \hline C_{iss} & - & 1600 & \\ \hline C_{oss} & - & 1600 & \\ \hline \end{array}$	$\begin{array}{c c c c c c c c c c c c c c c c c c c $

* Current is limited by package



MECHANICAL DIMENSIONS: in Inches / mm



PINOUT TABLE

DEVICE TYPE	PIN 1	PIN 2	PIN 3
N CHANNEL MOSFET IN A	DRAIN	SOURCE	GATE
TO-257 PACKAGE			



TECHNICAL DATA

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